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Diverging resistivity anisotropy with decreasing temperature in 60-K  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$ 

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The in-plane resistivity  $\rho_{ab}$  of 60-K  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$  is equal to  $(340 \pm 30) \mu\Omega \text{ cm}$  at 290 K and varies approximately linearly with temperature  $T$ . The anisotropy  $\rho_c/\rho_{ab}$  increases from  $\sim 100$  to 2000 as  $T$  decreases from 290 to 80 K. In the four crystals studied  $\rho_c$  is observed to increase monotonically with decreasing  $T$ . This is an intrinsic property of the normal state which has not been explained by conventional transport theory.

In the high- $T_c$  oxides the two-dimensional nature of the transport properties is one of the striking anomalies of the normal-state properties. Recent studies<sup>1-4</sup> have shown that the conductivity anisotropy is much greater than anticipated by band-structure calculations, or indicated by optical measurements.<sup>5</sup> In 90-K crystals of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$  (1:2:3) Hagen *et al.*<sup>2</sup> report that the anisotropy of the resistivity  $\rho_c/\rho_{ab}$  varies from  $\sim 80$  at 290 K to  $\sim 250$  near  $T_c$ , whereas "realistic" band-structure calculations<sup>6</sup> predict 10 to 20. In "two-plane"  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+y}$  (Bi 2:2:1:2), Martin *et al.*<sup>3</sup> find that  $\rho_c/\rho_{ab}$  grows to  $10^5$  as  $T$  decreases.

Even more interesting than the large anisotropy is the disparity in sign of the derivatives  $d\rho_c/dT$  and  $d\rho_{ab}/dT$ . As is well known, the in-plane resistivity  $\rho_{ab}$  is linear (or very close to linear) in the hole-type superconductors built up of  $\text{CuO}_2$  planes. In contrast, the out-of-plane resistivity  $\rho_c$  increases as  $T$  decreases. This was first observed by Tozer *et al.*<sup>1</sup> for 90-K 1:2:3, and confirmed by Hagen *et al.*<sup>2</sup> These results were contested by other groups<sup>7,8</sup> who report a strictly metallic variation in  $\rho_c$  in their "best" crystals.

The clarification of this point is important because it is clearly not possible within normal Fermi-liquid theory and the usual Bloch-Boltzmann approach to explain such a disparate  $T$  dependence in the two directions. The qualitatively different  $T$  dependence and the divergence of the ratio  $\rho_c/\rho_{ab}$  may be signatures of the peculiar normal state of these oxides, so it is important to investigate this point systematically. We have now extended the study of the resistivity anisotropy to the 60-K version  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$ , with the goal of studying the temperature dependence of both  $\rho_c$  and  $\rho_{ab}$ , and also to compare accurately the value of  $\rho_{ab}$  in the 60- and 90-K states of 1:2:3.

Following the procedure worked out for the ceramic samples,<sup>9</sup> we have reduced the oxygen content of crystals of the 90-K phase, which are grown using a BaO-CuO

flux.<sup>10</sup> The starting crystals all have very sharp transitions (measured both resistively and magnetically) between 91 and 93 K, and have been extensively studied.<sup>2,10</sup>  $\rho_{ab}$  is approximately  $150 \mu\Omega \text{ cm}$  at 290 K while  $\rho_c$  is of the order of  $10 \text{ m}\Omega \text{ cm}^2$ . Below 150 K,  $\rho_c$  shows a slight increase as  $T$  decreases towards  $T_c$ . To obtain the 60-K system, the 90-K crystals were reduced in an Ar atmosphere mixed with 8%  $\text{O}_2$  at a temperature of 573 °C for between 7 to 13 days. The ac susceptibility shows a superconducting transition between 60 and 70 K, and no trace of superconducting anomalies at higher  $T$ . The width of the transition is, however, much wider than in the original crystals, with the resistivity onset as high as 80 K (Sample 5). We note that, by starting with good homogeneous 90-K crystals, and reducing down to the 60-K phase, we arrive at an oxygen distribution which, if inhomogeneous, would be higher in the core. However, because of our long anneal times, and the susceptibility and resistivity results, we have reason to believe that the oxygen distribution is homogeneous. Fixing the annealing temperature and percentage of  $\text{O}_2$  in the reducing gas, we have doubled the annealing time and found very similar values for  $\rho_{ab}$  (Samples 4 and 5). In earlier attempts executed at lower annealing  $T$  or with shorter annealing times, we could detect a diamagnetic step between 80 and 90 K which indicated that part of the core remained in the  $\text{O}_7$  phase. Large decreases in  $\rho_{ab}$  above 80 K were also present in the partially reduced samples. Thick crystals ( $> 80 \mu\text{m}$  along  $c$ ) also tend to show such evidence of incomplete reduction. Our annealing process has been selected to achieve an oxygen content of 6.5–6.6 per unit cell. However, technical difficulties prevent the determination of the actual oxygen content in each crystal.

We used the Montgomery method<sup>11</sup> to measure  $\rho_{ab}$  and  $\rho_c$  separately. In some crystals we also used the van der Pauw method<sup>11</sup> to measure  $\rho_{ab}$ . Indium solder was used to attach the leads, but because the surface quality is quite

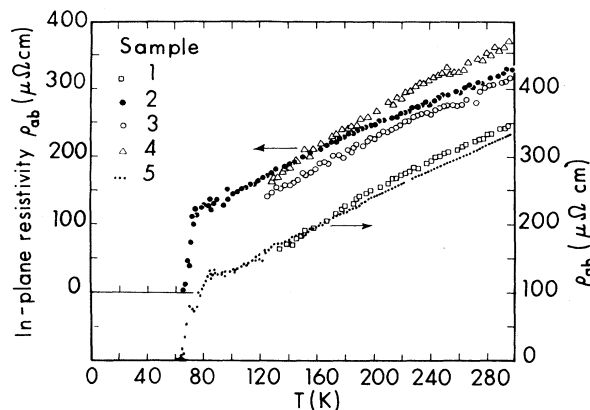


FIG. 1. The temperature dependence of  $\rho_{ab}$  in five samples of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$  reduced to the 60-K phase. Samples 1–4 are measured using Montgomery’s method. Sample 5 is measured using the van der Pauw technique.  $\rho_{ab}$  at 290 K lies between 315 and 370  $\mu\Omega$  cm. Data points for Samples 1, 3, and 4 are not reliable below 120 K because  $R_1$  is suppressed below our resolution (see text). Samples 1–5 were annealed at 573 °C for 8, 8, 10, 7, and 13 days, respectively.

poor after reduction, the contact resistance (50–200  $\Omega$ ) is much higher than in the 90-K crystals. Gentle scratching of the surface with a needle often improved the contacts. One of the major difficulties in this study is caused by the well-known exponential suppression of the lower resistance in the Montgomery technique.<sup>2</sup> This was a less serious problem in the 90-K phase because the anisotropy is smaller. Here, the larger anisotropy often suppresses the resistance in the direction nominally parallel to the  $\text{CuO}_2$  planes to the extent that it becomes unobservable. Thus, in some crystals, the data for  $\rho_{ab}$  only extend to 120 K. The van der Pauw method has been used to supplement our results for  $\rho_{ab}$  since it is free of this restriction. In all measurements the current is reversed to eliminate the contribution of thermal emf.

Figure 1 shows the temperature dependence of the in-plane resistivity for the five samples studied.  $\rho_{ab}$  is close to being linear in  $T$  in all samples, although it extrapolates to a finite value at  $T=0$ . In Samples 1, 3, and 4 the suppression of the in-plane potential drop is severe, so that the calculated  $\rho_{ab}$  shows very large fluctuations below 120 K. In all samples, the room-temperature value of  $\rho_{ab}$  is between 320 and 370  $\mu\Omega$  cm (average over the five samples is 340  $\mu\Omega$  cm). In view of the different measuring techniques, we consider this to be a fairly reliable estimate of the absolute resistivity in the 60-K phase. The value for the 90-K phase is 150  $\mu\Omega$  cm at 290 K.

The variation in the out-of-plane resistivity value is larger, ranging from 30 to 75 m $\Omega$  cm at 290 K (compared with  $\sim 10$  m $\Omega$  cm for the 90-K crystals). However, all four crystals studied show a strongly increasing  $\rho_c$  as  $T$  decreases. In Samples 1, 2, and 3  $\rho_c$  goes through a sharp peak near 80 K before decreasing to zero (see Fig. 2). We regard the peak as spurious, since the onset of superconducting behavior near 80 K greatly alters the current distribution, making the Montgomery separation of the con-

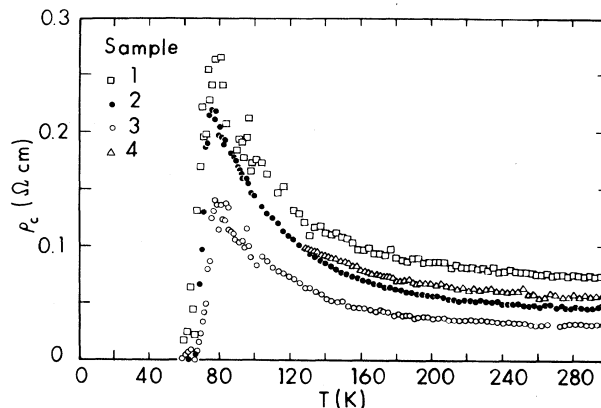


FIG. 2. Variation of  $\rho_c$  with  $T$  in four 60-K crystals of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$ , showing monotonic increase with decreasing  $T$ . The increased scatter below 120 K is caused by suppression of  $R_1$ .

tributions to the observed resistances highly unreliable.

Previous studies of the electrical anisotropy of 1:2:3 crystals focused on getting oxygen into highly deficient samples. The reduction of the peak in the  $\rho_c$  vs  $T$  profile with increasing oxygen content led some groups<sup>7,8</sup> to conclude that the peak was associated with an insulating core. We will argue that this interpretation is incorrect. By starting with crystals with  $\rho_{ab}$  much lower than those obtained even after long oxygen annealing, we reduce the oxygen content. This leads to an oxygen concentration which, if not uniform, must be larger in the core and smaller at the two  $ab$  faces. If we attribute the observed “semiconducting” behavior of  $\rho_c$  to one (or more) *uninterrupted* layers of insulating phase between the two faces, these layers must lie at the surface, i.e., directly under the contact pads. In the Montgomery technique the resistance is calculated with the current first nominally parallel, and then perpendicular, to the  $a$ - $b$  face ( $R_1$  and  $R_2$  respectively). It is clear that the putative existence of the insulating layers at the surface must affect both  $R_1$  and  $R_2$ , so that  $\rho_c$  and  $\rho_{ab}$  will show semiconducting behavior, in disagreement with our results. (This argument is inapplicable if the layer is in the core.) The observation of the same qualitative  $\rho_c$  vs  $T$  profile in four samples (with annealing times spanning 7 to 13 days) also makes it highly unlikely that the data are distorted by a pathological current distribution. We conclude that the  $\rho_c$  vs  $T$  profile is reproducible, and an intrinsic property of the 60-K phase. Whereas in the 90-K phase the upturn in  $\rho_c$  only occurs below 150 K,  $d\rho_c/dT$  here is negative even at 290 K. The magnitude of the anisotropy is also larger in the present system, increasing from  $\sim 100$  at 290 K to over 2000 at 80 K (Fig. 3). These numbers suggest that by removing oxygen from the chains, the system becomes more “two-dimensional,” and the qualitatively different behaviors of  $\rho_c$  and  $\rho_{ab}$  become more transparent. The rapid divergence of  $\rho_c$  with decreasing  $T$  implies the remarkable result that as  $T \rightarrow 0$ , the system tends to an insulator in the out-of-plane direction while the in-plane conduction remains metallic. The onset of superconduc-

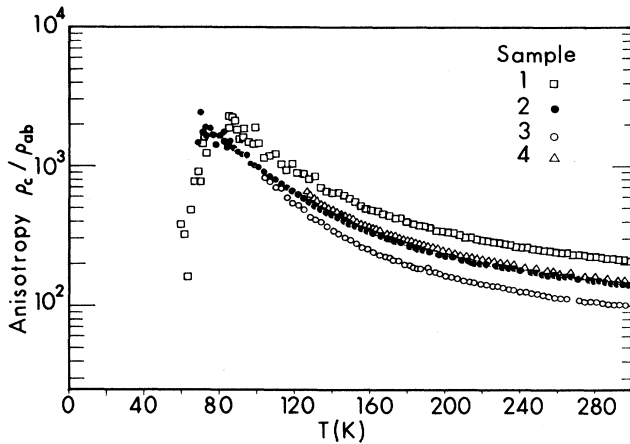


FIG. 3. The anisotropy of the resistivity in four crystals of 60-K  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$ .

tivity interrupts this trend, converting the system to a superconductor with sizable “effective-mass” anisotropy, but nowhere comparable with  $\rho_c/\rho_{ab}$  just above  $T_c$ .

As previously discussed for the 90-K phase, the different signs of  $d\rho_c/dT$  and  $d\rho_{ab}/dT$  in the high- $T_c$  oxides is unusual (if not unique) in highly anisotropic metals. There appears to be no way to account for such disparate behavior in conventional Bloch transport theory, even if one presupposes disorder leading to localization along  $c$ . The present study shows that  $\rho_c$  rises much more dramatically with decreasing  $T$  in the 60-K phase compared with either the 90-K phase<sup>2</sup> of 1:2:3 or Bi 2:2:1:2,<sup>3</sup> so that the difficulties with band-structure approaches are even more severe. Rather than the usual conventional Bloch-Boltzmann theory, the out-of-plane transport calls for a more sophisticated theory. (This is also the case for the thermopower<sup>12</sup> along  $c$ .) Anderson and Zou<sup>13</sup> proposed a mechanism based on the merging of spinons and holons which leads to a  $1/T$  behavior for  $\rho_c$ . The calculation itself has been criticized by Kallin and Berlinsky.<sup>14</sup> However, it remains of interest to check if  $\rho_c$  obeys the phenomenological expression  $\rho_c = AT + B/T$ . In Fig. 4 we plot  $\rho_c T$  vs  $T^2$  to compare the present results with the 90-K data. The plot shows that the increase in  $\rho_c$  below  $\sim 140$ – $200$  K is steeper than  $1/T$ . Above  $140$ – $200$  K, however, the data fall on a straight line as previously found for the 90-K system. The comparison shows that the phenomenological expression, as it stands, fails to describe the behavior of  $\rho_c$  over the whole temperature range. The deviation suggests a new process operating below  $140$ – $200$  K, or that an entirely different expression is needed.

We note that the conductivity along  $c$  ( $0.2$ – $0.3 \Omega \text{ cm}$  at  $80$  K) is  $20$  to  $30$  times smaller than the Mott-Ioffe-Regel (MIR) limit. Why is the conductivity along  $c$  so poor? Explanations based on Anderson localization<sup>15</sup> along  $c$  are unconvincing. To our knowledge, the coexistence of localization along  $c$ , with intraplane itinerant behavior has not been theoretically demonstrated for an anisotropic metal. To explain the present data, we would require very strong disorder along  $c$  (to produce the steep increase in  $\rho_c$ ).

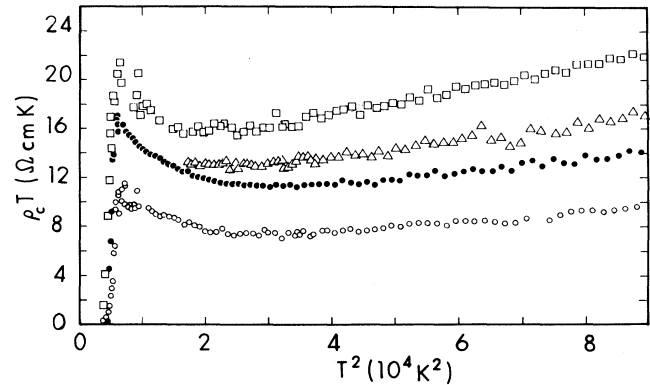


FIG. 4. Plot of  $\rho_c T$  vs  $T^2$  for four crystals of 60-K  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$  to compare data with the expression  $\rho_c = AT + B/T$ . Symbol identification is the same as in Fig. 3.

Yet, this disorder should not produce potential fluctuations strong enough to cause in-plane localization. We judge it highly unlikely that this highly specific pattern of disorder has been realized in the four annealed crystals. In any case, these are not strongly disordered solids (the in-plane conductivity is more consistent with a clean crystal).

The evidence points instead to a mechanism intrinsic to the unusual electronic states which strictly confines the charge carriers to each  $\text{CuO}_2$  plane. In the normal state, interplane transport occurs only when the confining mechanism is violated, for instance, by strong thermal fluctuations at elevated  $T$ . We believe that the strictly monotonic increase of  $\rho_c$  as  $T$  decreases requires the existence of such a confining mechanism. In Zou and Anderson’s theory the mechanism is the specific nature of the holes which can only exist in the planes. Interplane charge transfer requires scattering from spin excitations, which increase with  $T$ . Thus, increasing  $T$  leads to an enhancement of the out-of-plane transport, and a degradation of the in-plane conduction. (From recent studies of the thermal conductivity anisotropy, Hagen, Wang, and Ong<sup>16</sup> find that the electron-phonon coupling along  $c$  is very weak, so that phonons are not a likely candidate for the out-of-plane scattering.)

In summary, we have found that the out-of-plane resistivity increases with decreasing  $T$  in the 60-K phase of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-y}$ . The larger anisotropy ( $\sim 2000$  at  $80$  K) is consistent with the removal of oxygen from the chain sites. The increase is much more dramatic than in the 90-K phase.<sup>1,2</sup> Iye *et al.*<sup>7</sup> found that their crystals with higher  $T_c$ ’s have a metallic  $\rho_c$  while those with lower  $T_c$ ’s have a larger and “semiconducting”  $\rho_c$ . The general trend of  $d\rho_c/dT$  vs  $y$  in Ref. 7 is consistent with our finding, whereas the  $T$  dependence of  $\rho_c$  in the  $y = 7$  phase remains controversial.<sup>17</sup> Because of the conditions of sample preparation in the present work we are persuaded that the negative sign of  $d\rho_c/dT$  is an intrinsic property of the 60-K phase, rather than the result of “bad samples.” The evidence in favor of an *intrinsic* difference in signs for  $d\rho_c/dT$  and  $d\rho_{ab}/dT$  in the superconducting oxides based on  $\text{CuO}_2$  is now much stronger. This unusual property

may offer an important clue to the nature of the normal state.

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- <sup>17</sup>It is instructive to compare Sample *A* of Iye *et al.* (Ref. 7) with the data of Ref. 2 on 90-K crystals. In both studies,  $\rho_c$  is  $\sim 10$  m $\Omega$  cm at 100 K which is close to the MIR limit. However, in Iye *et al.*, the putative metallic behavior of  $\rho_c$  forces it to attain *twice* this value at 290 K with no sign of saturation. In Ref. 2,  $\rho_c$  is weakly  $T$  dependent, but shows a distinct increase with decreasing  $T$  near  $T_c$ . We suggest that there is significant contribution of the in-plane  $\rho_{ab}$  to Iye's measurement of  $\rho_c$ . Recent work on Nd<sub>2-x</sub>Ce<sub>x</sub>CuO<sub>4-y</sub> crystals in which the anisotropy exceeds 10<sup>4</sup> persuades us that, due to such contamination, it is easy to measure an apparently metallic  $\rho_c$  even when the deduced magnitude exceeds 5  $\Omega$  cm (500 times the MIR limit).